NSN 5961-01-303-5833

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-303-5833 **Inclosure Material:** Glass **Overall Length:** 0.280 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.150 inches **End Application:** Alq-135b countermeasure **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 reverse voltage, peak and 400.0 reverse voltage, instantaneous and 1.5 forward voltage, dc **Current Rating Per Characteristic:** 700.00 microamperes forward current, average major **Capacitance Rating In Picofarads:** 250.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Fast recovery diode; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No